

## Features

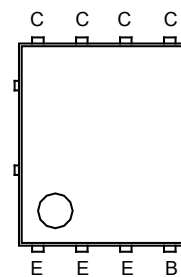
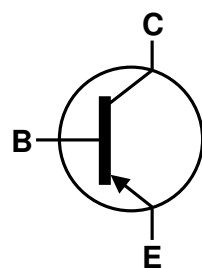
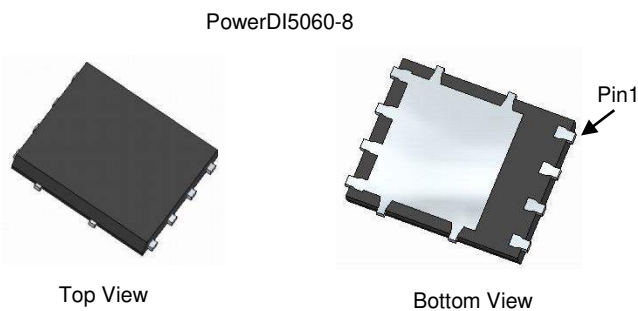
- $BV_{CEO} > -60V$
- $I_C = -3A$  Continuous Collector Current
- $I_{CM} = -8A$  Peak Pulse Current
- $R_{CE(SAT)} < 120\ m\Omega$
- Rated to  $+175^\circ C$ —Ideal for High Ambient Temperature Environments
- Complementary Part DXTN3C60PS
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

## Mechanical Data

- Case: PowerDI@5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish—Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 **Ⓜ3**
- Weight: 0.097 grams (Approximate)

## Applications

- Power Management
- Load Switch
- Linear Mode Voltage Regulator
- Backlighting Applications



Internal Schematic

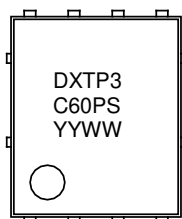
Top View  
Pin Configuration

## Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTP3C60PS-13	AEC-Q101	DXTP3C60PS	13	12	1000

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, see <http://www.diodes.com/products/packages.html>.

## Marking Information



DXTP3 = Product Type Marking Code  
 C60PS = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Last Digit of Year (ex: 18 = 2018)  
 WW = Week Code (01 to 53)

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Base Current	I <sub>B</sub>	-1	A
Continuous Collector Current	I <sub>C</sub>	-3	A
Peak Pulse Collector Current	I <sub>CM</sub>	-8	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

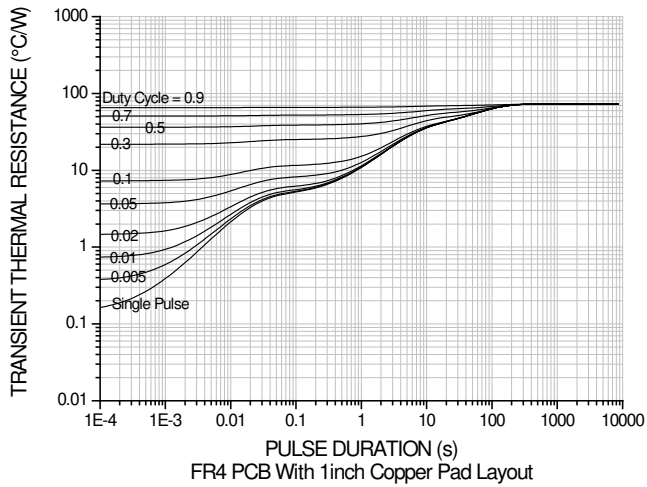
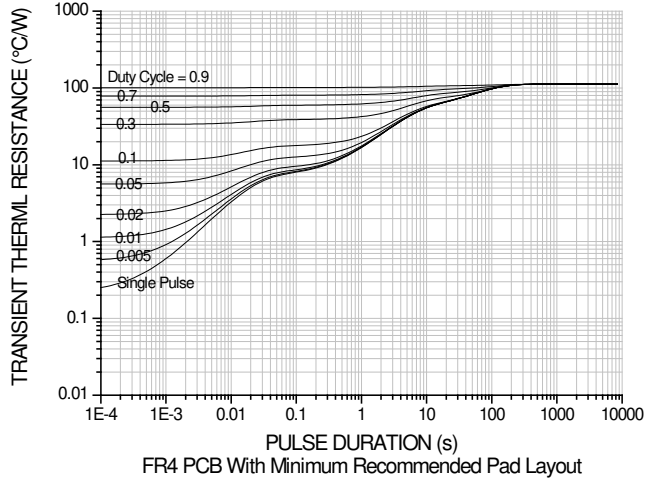
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P <sub>D</sub>	5	W
Thermal Resistance, Junction to Lead (Note 5)	R <sub>θJL</sub>	5.6	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>θJA</sub>	73	°C/W
		30 (Note 6)	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C

**ESD Ratings** (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 25mm × 25mm 1oz copper that is on single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
  6. Same as Note 5, except the device is measured at t ≤ 5 sec.
  7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

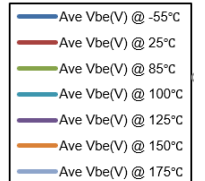
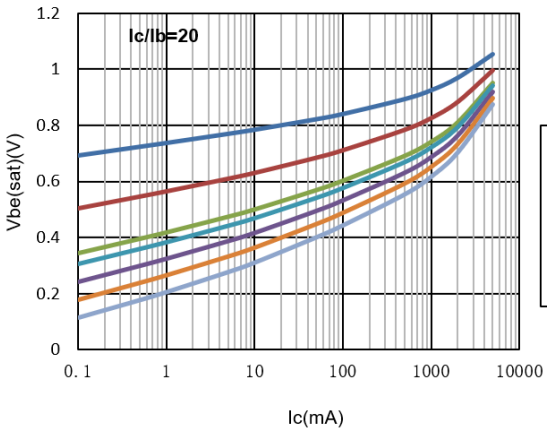
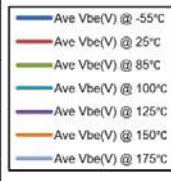
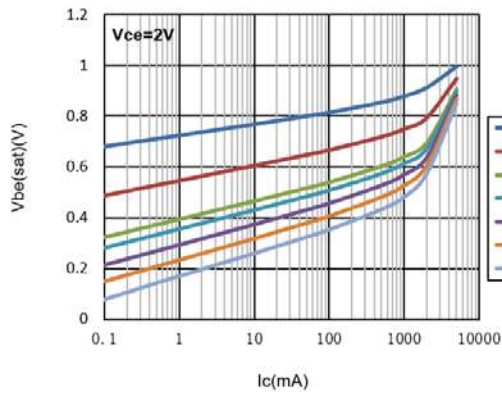
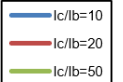
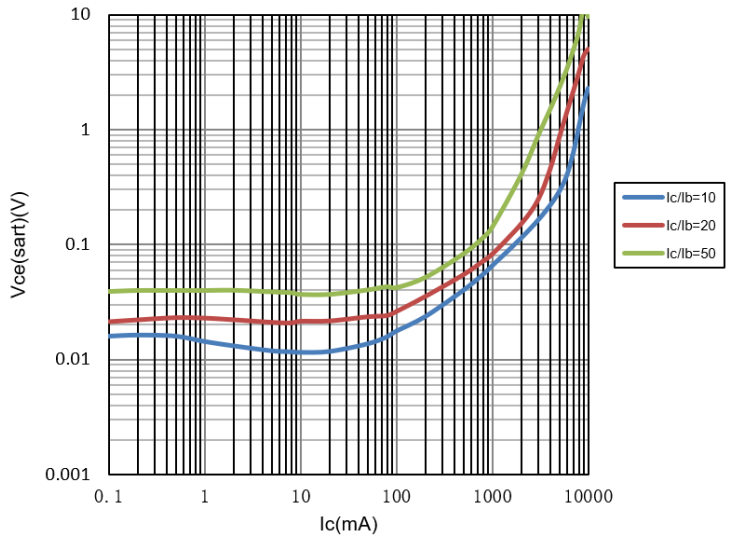
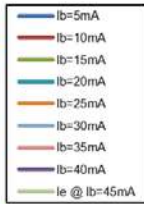
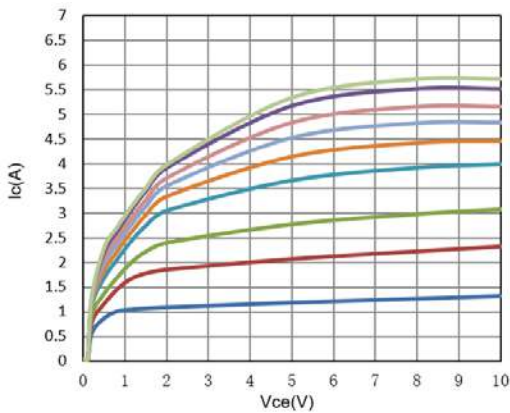
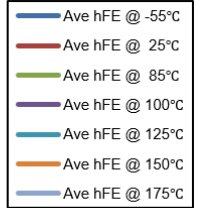
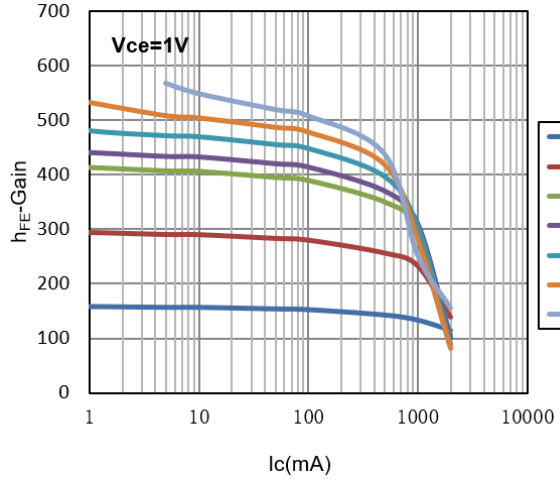
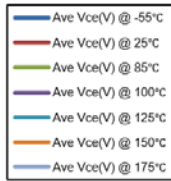
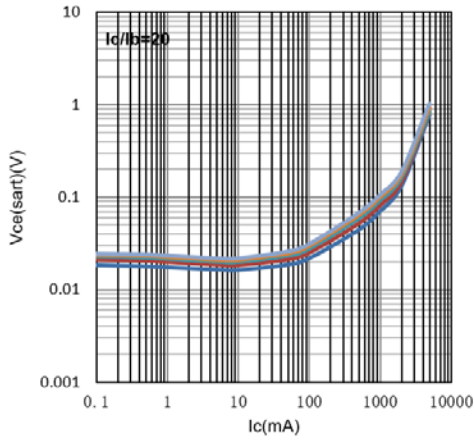


**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-60	—	—	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-60	—	—	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	—	—	V	I <sub>E</sub> = -100μA
Collector-Base Cutoff Current	I <sub>CBO</sub>	—	—	-100	nA	V <sub>CB</sub> = -48V
		—	—	-50	μA	V <sub>CB</sub> = -48V @ T <sub>j</sub> = 150°C
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	100	nA	V <sub>EB</sub> = -7V
Collector-Emitter Cutoff Current	I <sub>CES</sub>	—	—	100	nA	V <sub>CES</sub> = -48V
<b>ON CHARACTERISTICS</b> (Note 9)						
DC Current Gain	h <sub>FE</sub>	150	250	—	—	I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
		150	225	—		I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
		80	130	—		I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V
		35	75	—		I <sub>C</sub> = -3A, V <sub>CE</sub> = -2V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	—	-100	-225	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA
		—	-240	-360		I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Collector-Emitter Saturation Resistance	R <sub>CE(sat)</sub>	—	100	225	mΩ	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA
		—	80	120		I <sub>C</sub> = -3A, I <sub>B</sub> = -300mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	-0.8	-0.95	V	I <sub>C</sub> = -1A, I <sub>B</sub> = -50mA
		—	-1.02	-1.2		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>	—	-0.7	-0.8	V	I <sub>C</sub> = -0.5A, V <sub>CE</sub> = -2V
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Current Gain-Bandwidth Product	f <sub>T</sub>	—	—	—	MHz	V <sub>CE</sub> = -10V, I <sub>C</sub> = -500mA, f = 100MHz
Output Capacitance	C <sub>obo</sub>	—	42	—	pF	V <sub>CB</sub> = -10V, f = -1MHz
Delay Time	t <sub>d</sub>	—	15	—	ns	V <sub>CC</sub> = -12.5V, I <sub>C</sub> = 3A I <sub>B1</sub> = -I <sub>B2</sub> = -0.150A
Rise Time	t <sub>r</sub>	—	220	—	ns	
Turn-On Time	t <sub>(on)</sub>	—	235	—	ns	
Storage Time	t <sub>s</sub>	—	160	—	ns	
Fall Time	t <sub>f</sub>	—	185	—	ns	
Turn-Off Time	t <sub>(off)</sub>	—	345	—	ns	

Note: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)





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